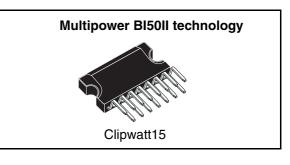


# **TDA7495SA**

## 11 W + 11 W amplifier with DC volume control

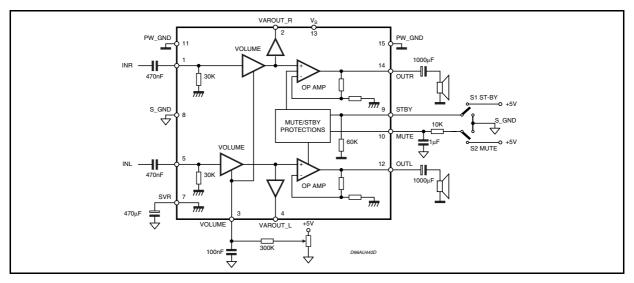
### Features

- 11 W + 11 W output power with R<sub>L</sub> = 8 Ω, THD = 10%, V<sub>CC</sub> = 28 V
- Stand-by and mute functions
- Low turn-on and turn-off "pop" noise
- Linear volume control DC coupled to power operational amplifier
- No boucherot cell
- No RC input network for stand-by
- Single supply up to 35 V
- Short-circuit protection
- Thermal overload protection
- Internally fixed gain
- Soft clipping
- Variable output after volume control circuit
- Clipwatt15 package, RoHS



### Description

The TDA7495SA is a stereo 11 W + 11 W class AB power amplifier specially designed for high-quality sound and TV applications. Its features include linear volume control, stand-by and mute functions. The TDA7495SA is delivered in the Clipwatt15 package



#### Table 1.Device summary

Order code	Package	Packaging
TDA7495SA	Clipwatt15	Tube

## 1 Pin connections



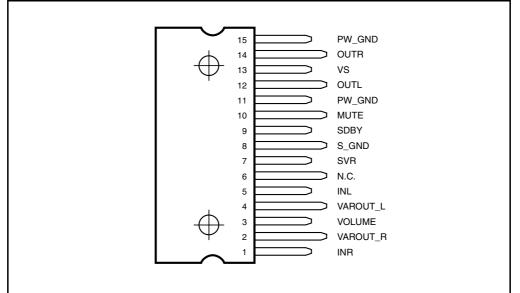


Table 2	. Pin	descri	ption
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Number	Name	Description
1	INR	Input, right channel
2	VAROUT_R	Volume control output, right channel
3	VOLUME	Adjust volume
4	VAROUT_L	Volume control output, left channel
5	INL	Input, left channel
6	N.C.	Not connected
7	SVR	Internal half supply bias
8	S_GND	Signal ground
9	STBY	Stand-by (active high)
10	MUTE	Mute (active high)
11	PW_GND	Power ground
12	OUTL	Output, left channel
13	VS	Power supply
14	OUTR	Output, right channel
15	PW_GND	Power ground



## 2 Electrical specifications

#### Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>S</sub>	DC supply voltage	35	V
V <sub>IN</sub>	Maximum input voltage	8	Vpp
P <sub>tot</sub>	Total power dissipation ( $T_{amb} = 70^{\circ} \text{ C}$ )	15	W
T <sub>amb</sub>	Ambient operating temperature	0 to 70	°C
T <sub>stg</sub> ,T <sub>J</sub>	Storage and junction temperature	-40 to 150	°C
V <sub>3</sub>	Volume control DC voltage	7	V

#### Table 4. Thermal data

Symbol	Parameter		Тур	Max	Unit
R <sub>th j-case</sub>	j-case Thermal resistance junction-case		4.5	5.0	°C/W
R <sub>th j-amb</sub> Thermal resistance junction-ambient			48		°C/W

Unless otherwise stated, the test conditions for the specifications given in *Table 5* below are: VS = 20 V,  $R_L = 8 \Omega$ , generator resistance  $Rg = 50 \Omega$ ,  $T_{amb} = 25^{\circ}$  C. Refer also to the application circuit of *Figure 2 on page 5*.

Table 5. Electrical characteristics	Table 5.
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Symbol	Parameter	Test condition	Min	Тур	Мах	Unit
Vs	Supply voltage range		11		35	V
l <sub>q</sub>	Total quiescent current			70	100	mA
DCV <sub>os</sub>	Output DC offset referred to SVR potential	No input signal	-650		650	mV
V <sub>O</sub>	Quiescent output voltage			10		V
		THD = 10%, V <sub>S</sub> = 28 V THD = 1%, V <sub>S</sub> = 28 V	9.5 7.5	11 8		w
P <sub>O</sub>	Output power	THD = 10%, V <sub>S</sub> = 20 V, R <sub>L</sub> = 4 $\Omega$ THD = 1%, V <sub>S</sub> = 20 V, R <sub>L</sub> = 4 $\Omega$	7 5	8 6		w
		THD = 10%, $V_S = 18 V$ THD = 1%, $V_S = 18 V$	3.5 2.2	3.8 2.9		w
THD	Total harmonic distortion	G <sub>v</sub> = 30 dB, P <sub>O</sub> = 1 W, f = 1 kHz			0.4	%
I <sub>peak</sub>	Peak output current	(internally limited)	1.7	2.4		A
V <sub>IN</sub>	Input signal				2.8	V RMS
Ri	Input resistance		22.5	30		kΩ
R <sub>VarOut</sub>	Output resistance at pins VAROUT_L, VAROUT_R			30	100	Ω



RL_VarOut         Load resistance which can be connected to pins AROUT_L, VAROUT_R         Comparine         VOLUME sets V         28.5         30.         31.5         dB           G_vine         Closed-loop gain         VOLUME sets V         28.5         30.         31.5         dB           G_vine         Volume control output at max gain         VOLUME sets V, RL_varout > 30 kΩ         -1.5         0.0         1.5         dB           AMin_vol         Attenuation at minimum volume setting         VOLUME < 0.5 V         80         .0         M         dB           BW         Attenuation at minimum volume setting         VOLUME < 0.5 V         80         .0         MHz           BW         Image Setting         VOLUME < 0.5 V         80         .0         MHz           BW         Image Setting         VOLUME < 0.5 V         80         .0         MHz           BW         Image Setting         VOLUME < 0.5 V         80         .0<	Symbol	Parameter	Test condition	Min	Тур	Max	Unit
$ \begin{array}{ c c c c } \hline \mbox{Volume control output at} \\ \hline \mbox{Volume setting} \\ \hline Volume set$	R <sub>L_VarOut</sub>	be connected to pins		2			kΩ
$ \begin{array}{ c c c c c c c } \hline \mbox{max gain} & $	G <sub>v</sub>	Closed-loop gain	VOLUME >4.5 V	28.5	30	31.5	dB
$\begin{array}{c c c c c c c c } \hline Muin_VOL} & volume setting & VOLUME < 0.5 V & 80 & C & C & C & M \\ \hline M & M \\ \hline BW & & M \\ \hline SW & M \\ \hline M \\ M \\ M \\ \hline M \\ M \\ \hline \ M \\ \hline \ M \\ \hline \ M \\ \hline \ M \\ \hline \ M \\ \hline \hline \ M \\ \hline \ M \\ \hline \ M \\ \hline \hline \ M \\ \hline \ M \\ \hline \ M \\ \hline \ M \\ \hline \hline \ M \\ \hline \ M \\ \hline \ \ M \\ \hline \hline \ M \\ \hline \ \ M \\ \hline \hline \ M \\ \hline \hline \ \ M \\ \hline \hline \ \ M \\$	G <sub>vline</sub>	-		-1.5	0	1.5	dB
$ \begin{array}{c c c c c c } & \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $	A <sub>Min_VOL</sub>		VOLUME < 0.5 V	80			dB
	BW				0.6		MHz
$ \frac{max attenuation}{f = 20 Hz to 22 kHz MUTE} = 100 250 \muV \\ \frac{max attenuation}{f = 20 Hz to 22 kHz MUTE} = 100 250 \muV \\ \frac{100}{F = 20 Hz to 22 kHz MUTE} = 100 150 \muV \\ \frac{100}{F = 20 Hz to 22 kHz MUTE} = 5 8 0 V/\muS \\ \frac{100}{F = 1 kHz; max volume} \\ \frac{100}{SVR} = 1 V RMS 35 39 39 dB \\ \frac{100}{F = 1 kHz; max volume} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 dB \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 65 \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 \\ \frac{100}{F = 1 kHz; max attenuation} \\ \frac{100}{SVR} = 100 PH \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS 55 \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 1 V RMS \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 5 V V_{RIP} = 5 V V_{RIP} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 5 V V_{RIP} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} = 5 V V_{RIP} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} \\ \frac{100}{SVR} = 470 \muF; V_{RIP} \\ \frac{100}{SVR} = $					500	800	μV
SR         Slew rate         5         8         V/us           SVR         Supply voltage rejection $\int_{1}^{1} 1 kHz; max volume C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS}{f = 1 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS}$ $35$ $39$ $dB$ TM         Thermal muting $1 = 1 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS}$ $55$ $65$ $dB$ TM         Thermal muting $1 = 1 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS}$ $55$ $65$ $dB$ TM         Thermal muting $1 = 1 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS}$ $55$ $65$ $dB$ TM         Thermal shut-down $1 = 0 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS}$ $160$ $\circ C$ TM         Thermal shut-down $1 = 0 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS}$ $160$ $\circ C$ TM         Thermal shut-down $1 = 0 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS$ $160$ $\circ C$ VMute         Thermal shut-down $1 = 0 kHz; max attenuation C_{SVR} = 470 \muF; V_{RIP} = 1 V RMS$ $2.3 2.5 2.7$ $V$ $V_{MUTE}$ Mute threshold $1 = 0 kHz; max attenuation C_{SVR} = 5 V, Mute = 5 V$	e <sub>N</sub>	Total output noise			100	250	μV
SVRSupply voltage rejection $f = 1 \text{ kHz; max volume} C_{SVR} = 470 \ \mu\text{F; V}_{RIP} = 1 \ V \text{ RMS}}$ 3539dBTMThermal muting $55$ $65$ $dB$ TMThermal muting $55$ $65$ $c$ $c$ TSThermal shut-down $100$ $c$ $c$ $c$ Mute, stard-by and input selection $t$ $160$ $c$ $c$ VSTBYStand-by threshold $c$ $c$ $c$ $c$ $V_{\text{MUTE}}$ Mute threshold $c$ $c$ $c$ $c$ $I_qSTBY$ Quiescent current in stand-by $c$ $c$ $c$ $c$ $I_{\text{STBY}}$ Bias current for pin STBY $r$ $r$ $r$ $r$ $I_{\text{MUTEEbias}}$ Bias current for pin MUTE $r$ $r$ $r$ $r$ $I_{\text{MUTEbias}}$ Bias current for pin MUTE $r$ $r$ $r$ $r$ $I_{\text{MUTEbias}}$ Bias current for pin MUTE $r$ $r$ $r$ $r$ $I_{\text{MUTEbias}}$ Bias current for pin MUTE $r$ $r$ $r$ $r$ $I_{\text{MUTEbias}}$ Bias current for pin MUTE $r$ $r$ $r$ $r$ $r$ $I_{\text{MUTEbias}}$ Bias current for pin MUTE $r$ $r$ $r$ $r$ $r$ $r$ $I_{\text{MUTEbias}}$ Bias current for pin MUTE $r$ $r$ $r$ $r$ $r$ $r$			f = 20 Hz to 22 kHz MUTE		60	150	μV
SVRSupply voltage rejection $C_{SVR} = 470 \ \mu\text{F}; \ V_{RIP} = 1 \ V \ RMS}$ $33^{35}$ $39^{36}$ $10^{35}$ TMThermal muting $55^{36}$ $65^{36}$ $dB^{36}$ TMThermal muting $150^{36}$ $\circ C$ TSThermal shut-down $150^{36}$ $\circ C$ Mute, stard-by and input selection functions $160^{36}$ $\circ C$ VSTBYStand-by threshold $2.3^{36}$ $2.5^{36}$ $2.7^{36}$ VMUTEMute threshold $2.3^{36}$ $2.5^{36}$ $2.7^{36}$ $I_{qSTBY}$ Quiescent current in stand-by $2.3^{36}$ $2.5^{36}$ $2.7^{36}$ $I_{STBYbias}$ Bias current for pin STBYIn stand-by mode, $V_{STBY} = 5 \ V, \ V_{MUTE} = 5 \ V$ $80^{36}$ $\mu^{A}$ $I_{MUTEbias}$ Bias current for pin MUTEIn mute mode $-20^{36}$ $-5^{36}$ $\mu^{A}$	SR	Slew rate		5	8		V/µs
Image: Second	SVR Supply voltage rejectior			35	39		dB
TSThermal shut-downInclusionInclusionInclusionInclusionMute, stand-by and input selection functions $160$ $^{\circ}$ CMute, stand-by and input selection functions $2.3$ $2.5$ $2.7$ $V$ $V_{\text{MUTE}}$ Mute threshold $2.3$ $2.5$ $2.7$ $V$ $V_{\text{MUTE}}$ Mute threshold $2.3$ $2.5$ $2.7$ $V$ $I_{qSTBY}$ Quiescent current in stand-by $0.6$ $1$ $mA$ $A_{\text{MUTE}}$ Mute attenuation $50$ $65$ $dB$ $I_{\text{STBYbias}}$ Bias current for pin STBYIn stand-by mode, $V_{\text{STBY}} = 5$ V, $V_{\text{MUTE}} = 5$ V $80$ $\mu$ $I_{\text{MUTEbias}}$ Bias current for pin MUTEIn mute mode $-20$ $-5$ $\mu$		Supply volage rejection		55	65		dB
Mute, stand-by and input selection functions $V_{STBY}$ Stand-by threshold2.32.52.7V $V_{MUTE}$ Mute threshold2.32.52.7V $I_{qSTBY}$ Quiescent current in stand-by0.61mA $A_{MUTE}$ Mute attenuation5065dB $I_{STBYbias}$ Bias current for pin STBYIn stand-by mode, $V_{STBY} = 5 V$ , $V_{MUTE} = 5 V$ 80 $\mu A$ $I_{MUTEbias}$ Bias current for pin MUTEIn mute mode-20-5 $\mu A$	ТМ	Thermal muting			150		°C
VSTBYStand-by threshold2.32.52.7VVMUTEMute threshold2.32.52.7VIqSTBYQuiescent current in stand-by0.61mAAMUTEMute attenuation50650.6dBISTBYbiasBias current for pin STBYIn stand-by mode, VSTBY = 5 V, VMUTE = 5 V80 $\mu A$ IMUTEbiasBias current for pin MUTEIn mute mode-20-5 $\mu A$	TS	Thermal shut-down			160		°C
V_{MUTE}Mute threshold2.32.52.7V $I_{qSTBY}$ Quiescent current in stand-by0.61mA $A_{MUTE}$ Mute attenuation5065dB $I_{STBYbias}$ Bias current for pin STBYIn stand-by mode, $V_{STBY} = 5 V$ , $V_{MUTE} = 5 V$ 80 $\mu A$ $I_{MUTEbias}$ Bias current for pin MUTEIn mute mode-20-5 $\mu A$	Mute, sta	nd-by and input selection	functions				
INOTEQuiescent current in stand-byImage: Constraint of the stand of th	V <sub>STBY</sub>	Stand-by threshold		2.3	2.5	2.7	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	V <sub>MUTE</sub>	Mute threshold		2.3	2.5	2.7	V
$\frac{I_{\text{STBYbias}}}{I_{\text{MUTEbias}}} \xrightarrow{\text{Bias current for pin MUTE}} \frac{In stand-by mode,}{In play or mute mode} \xrightarrow{10} \frac{10}{10} \xrightarrow{10} \xrightarrow{10} \frac{10}{10} \xrightarrow{10} \frac{10}{10} \xrightarrow{10} \xrightarrow{10} \xrightarrow{10} \xrightarrow{10} \frac{10}{10} \xrightarrow{10} \xrightarrow{10}$	I <sub>qSTBY</sub>				0.6	1	mA
ISTBYbiasBias current for pin STBY $V_{STBY} = 5 V, V_{MUTE} = 5 V$ oo $\mu A$ In play or mute mode-20-5 $\mu A$ In mute mode15 $\mu A$	A <sub>MUTE</sub>	Mute attenuation		50	65		dB
In play or mute mode     -20     -5     μA       In mute mode     In mute mode     1     5     μA	I <sub>STBYbias</sub>	Bias current for pin STBY			80		μA
I <sub>MUTEbias</sub> Bias current for pin MUTE			In play or mute mode	-20	-5		μA
	l		In mute mode		1	5	μA
	'MUTEbias		In play mode		0.2	2	μA

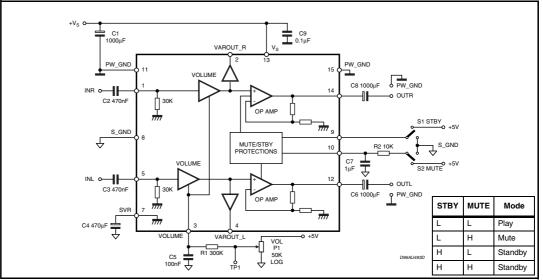
 Table 5.
 Electrical characteristics (continued)



## 3 Applications

#### 3.1 Circuit diagram and components

#### Figure 2. Application circuit



The recommended values of the external components are those shown on the application circuit of *Figure 2. Table 6* below indicates how the performance changes when component values different to the recommended are used.

Symbol	Suggested value	Purpose	Larger than suggestion	Smaller than suggestion
R1	300 kΩ	Volume control circuit	Larger volume regulation time	Smaller volume regulation time
R2	10 kΩ	Mute time constant	Larger mute on/off time	Smaller mute on/off time
P1	50 kΩ	Volume control		
C1	1000 µF	Supply voltage decoupling		Danger of oscillation
C2, C3	470 nF	Input AC coupling	Lower low-frequency cutoff	Higher low-frequency cutoff
C4	470 µF	Ripple rejection	Better SVR	Worse SVR
C5	100 nF	Volume control time constant	Larger volume regulation time	Smaller volume regulation time
C6, C8	1000 µF	Output AC coupling	Lower low-frequency cutoff	Higher low-frequency cutoff
C7	1 µF	Mute time constant	Larger mute on/off time	Smaller mute on/off time
C9	100 nF	Supply voltage decoupling		Danger of oscillation

#### Table 6. Application suggestions



### 3.2 Board layout

Figure 3. PCB and component layout

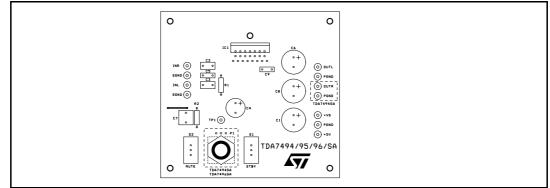


Figure 4. Evaluation board bottom layer layout

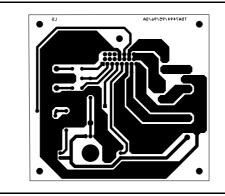
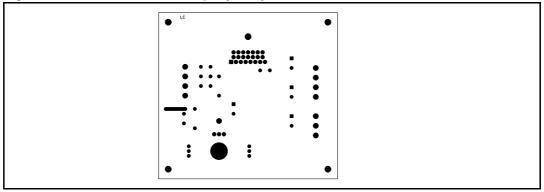


Figure 5. Evaluation board top layer layout



### 3.3 Power-up/down sequence

In order to reduce the loud speaker "pop" noise when switching the device on or off we recommend that you follow the sequence of operations shown in *Figure 6* below.

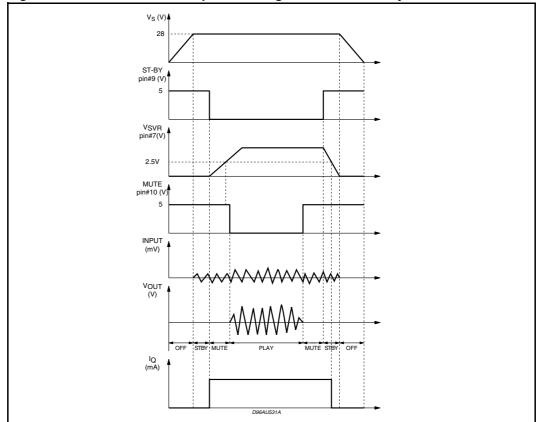


Figure 6. Recommended sequence using mute and stand-by functions

#### Using the mute function only

To simplify the application, pin STBY can be connected directly to ground so that the device is always active. Then, to maintain the power-up/down performance you should adhere to the following conditions:

- At turn-on the transition mute to play must be made when pin SVR is higher than 2.5 V.
- At turn-off the TDA7495SA must be set to mute from the play condition before pin SVR falls below 2.5 V.



### 3.4 Typical electrical characteristics

Unless otherwise stated, the test conditions for the electrical characteristics given in the figures below are: VS = 20 V,  $R_L = 8 \Omega$ , f = 1 kHz, generator resistance  $R_g = 50 \Omega$ ,  $T_{amb} = 25^{\circ}$  C. Refer also to the application circuit of *Figure 2 on page 5*.



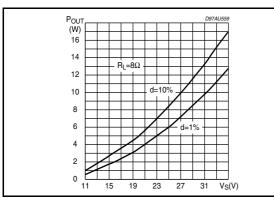


Figure 9. Distortion vs output power

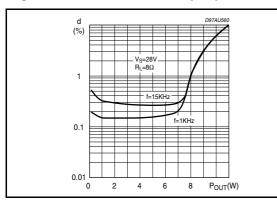
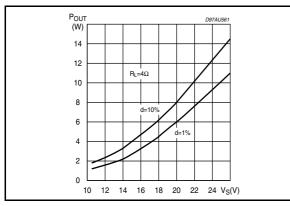
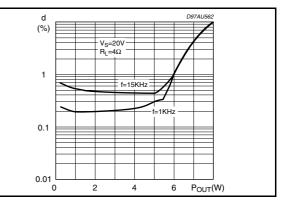


Figure 11. Output power vs supply voltage







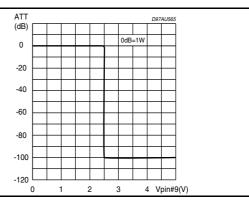
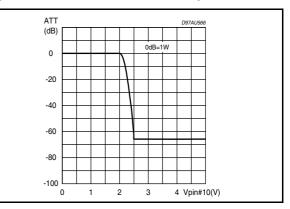


Figure 12. Mute attenuation vs Vpin#10



57

Figure 13. Supply voltage vs frequency

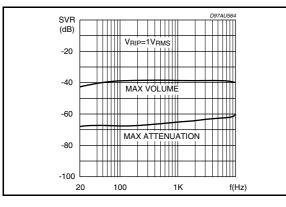
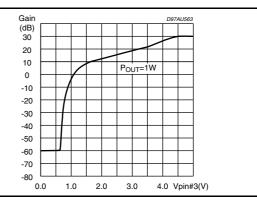
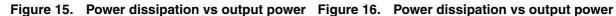
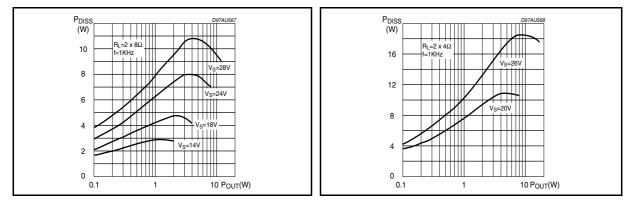


Figure 14. Gain vs volume control voltage (#3)



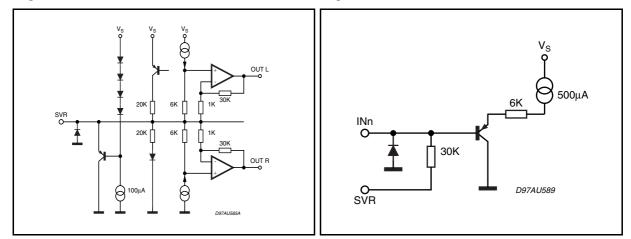




### 3.5 Internal equivalent circuits

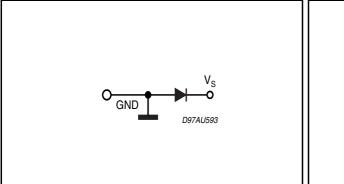
Figure 17. Pin: SVR

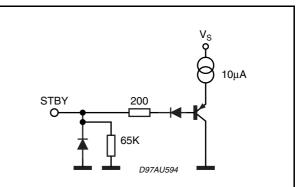
Figure 18. Pins: INL, INR



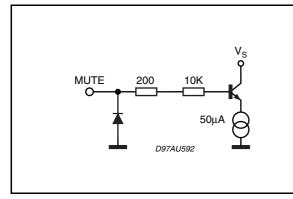
#### Figure 19. Pins: PW-GND, S-GND

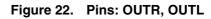
Figure 20. Pin: STBY











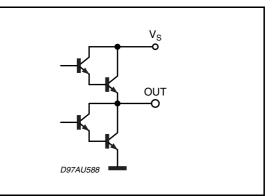
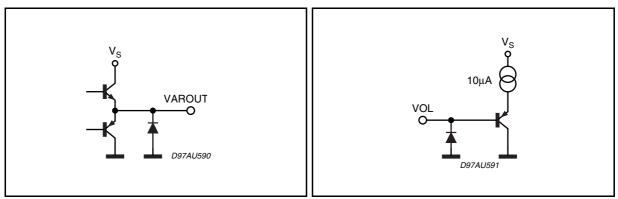


Figure 23. Pins: VAROUT\_L, VAROUT\_R

Figure 24. Pin: VOLUME





### 4 Thermal considerations

In order to avoid the intervention of the thermal protection, it is important to choose an adequate heatsink.

The parameters that influence the heatsink size are:

- maximum dissipated power for the device (P<sub>dmax</sub>)
- maximum thermal resistance junction to case (R<sub>Th j-c</sub>)
- maximum ambient temperature T<sub>amb\_max</sub>

Example:

For V<sub>CC</sub> = 20 V, R<sub>L</sub> = 8 
$$\Omega$$
, R<sub>Th j-c</sub> = 5° C/W, T<sub>amb\_max</sub> = 50° C

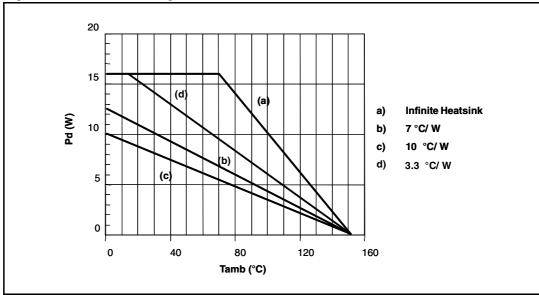
$$P_{dmax} = Number_of_channels * \frac{V_{cc}^2}{2\Pi^2 \cdot R_L} = 5 W$$

For the heatsink,

$$R_{Th j-c} = \frac{150 - T_{amb\_max}}{P_{d max}} - R_{Th j-c} = \frac{100}{5} - 5 = 15^{\circ}C/W$$

Figure 25 shows the power derating curve for the device.

Figure 25. Power derating curve



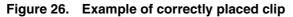
## 5 Clipwatt mounting suggestions

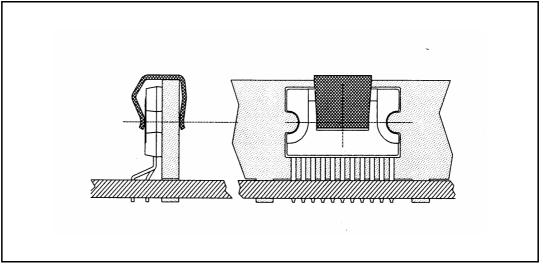
The suggested method for securing the Clipwatt package on an external heat sink is by a spring clip placed as close as possible to the center of the plastic body, as indicated in the example of *Figure 26*.

Thermal grease can be used to further reduce the thermal resistance of the contact between package and heatsink.

The clip should apply a force of 7 - 10 kg to provide sufficient pressure for a good contact. Care must be taken to ensure that the contact pressure on the package does not exceed 15 kg/mm<sup>2</sup>.

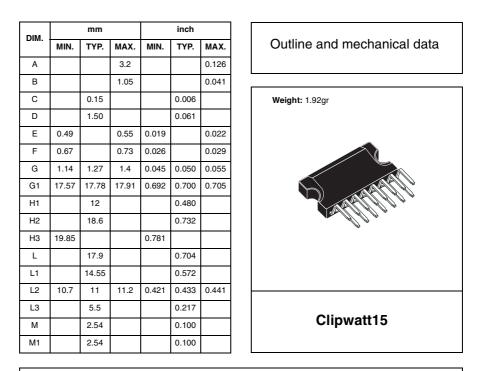
As an example, if the clip applies a 15-kg force on the package then the clip must have a contact area of at least 1 mm<sup>2</sup>.

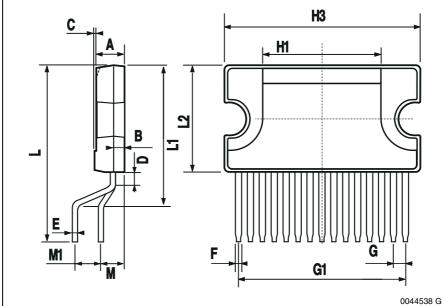




### 6 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.





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## 7 Revision history

#### Table 7.Document revision history

Date	Revision	Description
Sep 2003	1	Initial release
11-Dec 2007	2	Updated package and PCB information



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